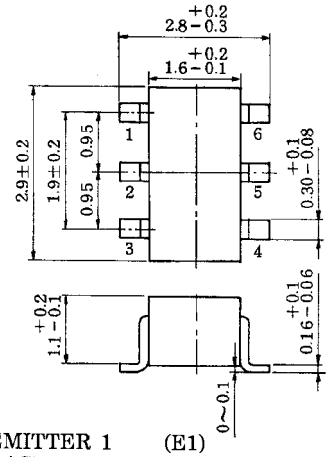
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

RN1607,RN1608,RN1609

Switching, Inverter Circuit, Interface Circuit
And Driver Circuit Applications

- Including two devices in SM6 (super mini type with 6 leads)
- With built-in bias resistors.
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2607~RN2609

Unit: mm

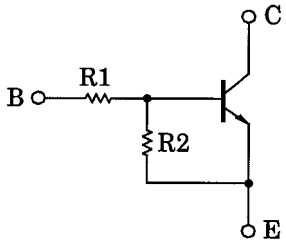


1. EMITTER 1 (E1)
2. BASE 1 (B1)
3. COLLECTOR 2 (C2)
4. EMITTER 2 (E2)
5. BASE 2 (B2)
6. COLLECTOR 1 (C1)

JEDEC	—
EIAJ	—
TOSHIBA	2-3N1A

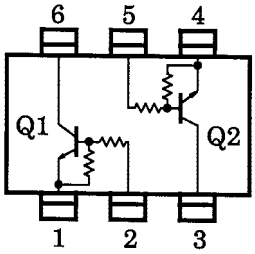
Weight: 0.015g

Equivalent Circuit and Bias Resistor Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN1607	10	47
RN1608	22	47
RN1609	47	22

Equivalent Circuit (Top View)



Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

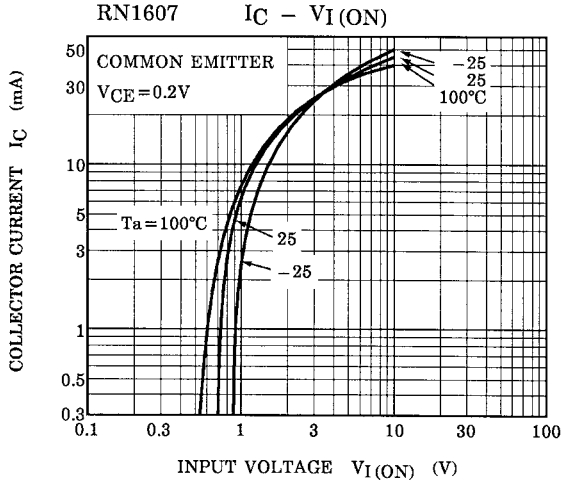
Characteristic		Symbol	Rating	Unit
Collector-base voltage	RN1607~1609	V_{CBO}	50	V
Collector-emitter voltage		V_{CEO}	50	V
Emitter-base voltage	RN1607	V_{EBO}	6	V
	RN1608		7	
	RN1609		15	
Collector current	RN1607~1609	I_C	100	mA
Collector power dissipation		P_C	300	mW
Junction temperature		T_j	150	°C
Storage temperature range		T_{stg}	−55~150	°C

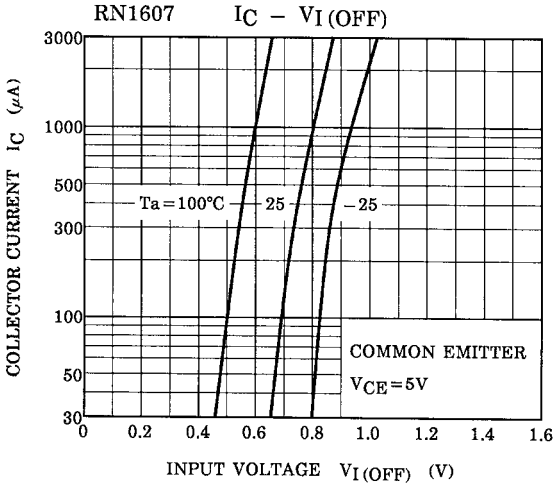
* Total rating

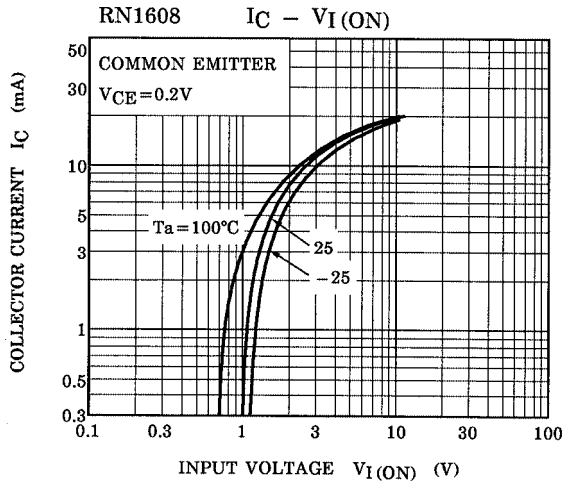
Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

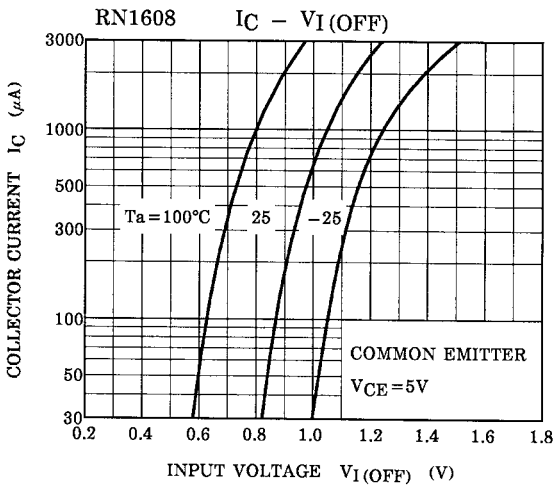
Characteristic		Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	RN1607~1609	I_{CBO}	—	V_{CB} = 50V, I_E = 0	—	—	100	nA
		I_{CEO}	—	V_{CE} = 50V, I_B = 0	—	—	500	nA
Emitter cut-off current	RN1607	I_{EBO}	—	V_{EB} = 6V, I_C = 0	0.081	—	0.15	mA
	RN1608		—	V_{EB} = 7V, I_C = 0	0.078	—	0.145	
	RN1609		—	V_{EB} = 15V, I_C = 0	0.167	—	0.311	
DC current gain	RN1607	h_{FE}	—	V_{CE} = 5V, I_C = 10mA	80	—	—	—
	RN1608		—		80	—	—	
	RN1609		—		70	—	—	
Collector-emitter saturation voltage	RN1607~1609	$V_{CE\ (sat)}$	—	I_C = 5mA, I_B = 0.25mA	—	0.1	0.3	V
Input voltage (ON)	RN1607	$V_{I\ (ON)}$	—	V_{CE} = 0.2V, I_C = 5mA	0.7	—	1.8	V
	RN1608		—		1.0	—	2.6	
	RN1609		—		2.2	—	5.8	
Input voltage (OFF)	RN1607	$V_{I\ (OFF)}$	—	V_{CE} = 5V, I_C = 0.1mA	0.5	—	1.0	V
	RN1608		—		0.6	—	1.16	
	RN1609		—		1.5	—	2.6	
Translation frequency	RN1607~1609	f_T	—	V_{CE} = 10V, I_C = 5mA	—	250	—	MHz
Collector output capacitance	RN1607~1609	C_{ob}	—	V_{CB} = 10V, I_E = 0, f = 1MHz	—	3	6	pF
Input resistor	RN1607	R1	—	—	7	10	13	kΩ
	RN1608		—		15.4	22	28.6	
	RN1609		—		32.9	47	61.1	
Resistor ratio	RN1607	R1/R2	—	—	0.191	0.213	0.232	—
	RN1608		—		0.421	0.468	0.515	
	RN1609		—		1.92	2.14	2.35	

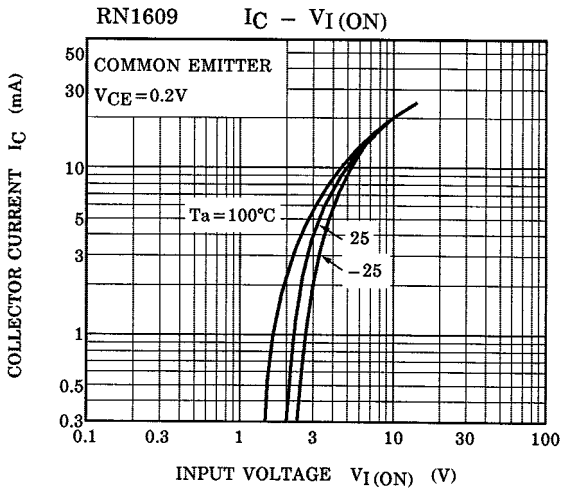
(Q1, Q2 Common)

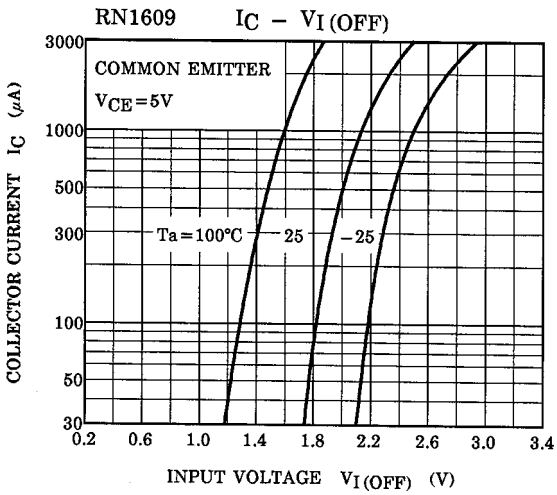

RN1607 I_C – $V_{I(ON)}$
COMMON EMITTER
V_{CE}=0.2V
Ta=100°C
25
−25
−25
25
100°C
COLLECTOR CURRENT I_C (mA)
INPUT VOLTAGE $V_{I(ON)}$ (V)


RN1607 I_C – $V_{I(OFF)}$
Ta=100°C
25
−25
COMMON EMITTER
V_{CE}=5V
COLLECTOR CURRENT I_C (μA)
INPUT VOLTAGE $V_{I(OFF)}$ (V)


RN1608 I_C – $V_{I(ON)}$
COMMON EMITTER
V_{CE}=0.2V
Ta=100°C
25
−25
COLLECTOR CURRENT I_C (mA)
INPUT VOLTAGE $V_{I(ON)}$ (V)

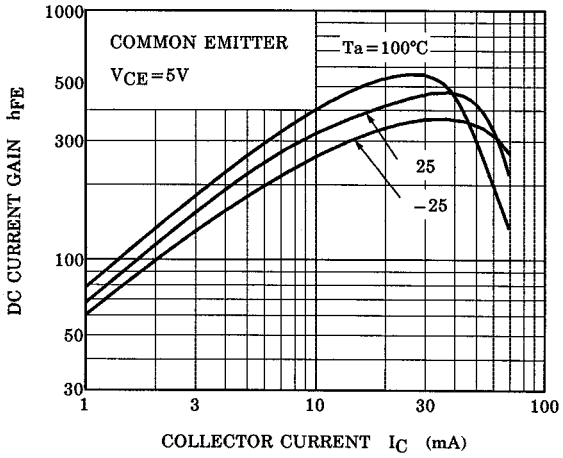

RN1608 I_C – $V_{I(OFF)}$
Ta=100°C
25
−25
COMMON EMITTER
V_{CE}=5V
COLLECTOR CURRENT I_C (μA)
INPUT VOLTAGE $V_{I(OFF)}$ (V)


RN1609 I_C – $V_{I(ON)}$
COMMON EMITTER
V_{CE}=0.2V
Ta=100°C
25
−25
COLLECTOR CURRENT I_C (mA)
INPUT VOLTAGE $V_{I(ON)}$ (V)

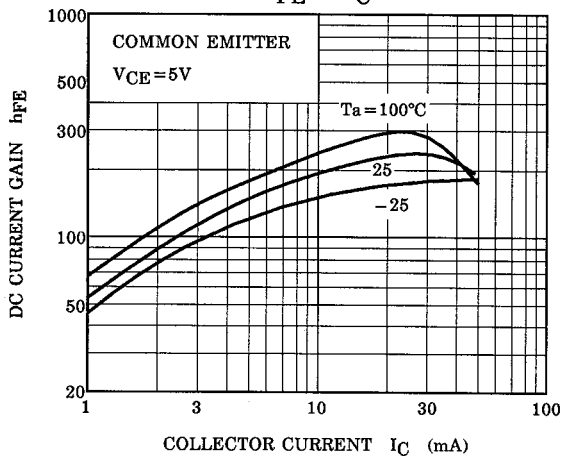

RN1609 I_C – $V_{I(OFF)}$
COMMON EMITTER
V_{CE}=5V
Ta=100°C
25
−25
COLLECTOR CURRENT I_C (μA)
INPUT VOLTAGE $V_{I(OFF)}$ (V)

(Q1, Q2 Common)

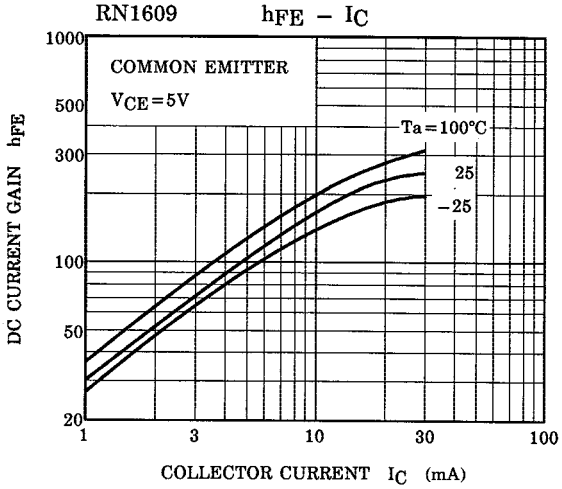
RN1607 h_{FE} – I_C

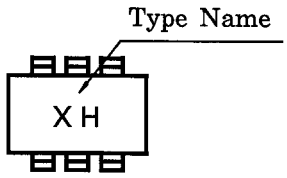
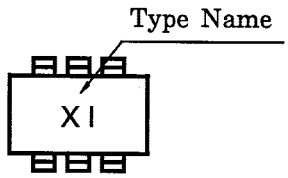
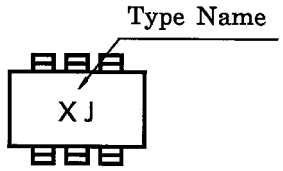


RN1608 h_{FE} – I_C



RN1609 h_{FE} – I_C



Type Name	Marking
RN1607	
RN1608	
RN1609	

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